NSN 5962-01-340-7820

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Overall Height: 0.425 inches Body Length:



View Online at https://aerobasegroup.com/nsn/5962-01-340-7820

1.290 inches
Body Width:
Between 0.500 inches and 0.610 inches
Body Height:
Between 0.150 inches and 0.210 inches
Maximum Power Dissipation Rating:
635.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and burn in and monolithic and ultraviolet erasable
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
N-type metal oxide-semiconductor logic
Input Circuit Pattern:
13 input
Case Outline Source And Designator:
D-3 mil-m-38510
Current Rating Per Characteristic:
115.00 milliamperes reverse current, dc absolute
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-300.0 millivolts power source and 6.0 volts power source
Capitance Rating Per Characteristic:
Err-060
Time Rating Per Chacteristic:
450.00 nanoseconds af output megawatts
Memory Device Type:
Eprom
Unpackaged Unit Weight:
6.5 grams
Test Data Document:
96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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Terminal Type Ar	nd Quantity:
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24 printed circuit

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

A458a0